TPD4E002 Quad Low-Capacitance Array with ±15-kV ESD Protection

1 Features
- IEC 61000-4-2 ESD Protection
  - ±15-kV IEC 61000-4-2 Contact Discharge
- IEC 61000-4-5 Surge Protection
  - 2.5-A Peak Pulse Current (8/20-μs Pulse)
- ANSI/ESDA/JEDEC JS-001
  - ±15-kV Human Body Model (HBM)
- Four Unidirectional Voltage Suppression Diodes for use in ESD Protection
- I/O Breakdown Voltage, $V_{BR} = 6.1$ V (Minimum)
- I/O Capacitance 11 pF (Typical)
- Low Leakage Current < 100 nA
- Very Small Printed-Circuit Board (PCB) Area < 2.6 mm$^2$
- High Integration
- Suitable for High-Density Boards

2 Applications
- Computers
- Printers
- Communication Systems and Cellular Phones
- Video Equipment

3 Description
The TPD4E002 device is a transient voltage suppressor (TVS) designed to protect up to four lines against electrostatic discharge (ESD) transients. The monolithic circuit design allows superior capacitance matching between the channels and reduced crosstalk. This device is ideal for applications where both reduced line capacitance and board space-saving are required.

Device Information

<table>
<thead>
<tr>
<th>PART NUMBER</th>
<th>PACKAGE</th>
<th>BODY SIZE (NOM)</th>
</tr>
</thead>
<tbody>
<tr>
<td>TPD4E002</td>
<td>SOT (5)</td>
<td>1.60 mm × 1.20 mm</td>
</tr>
</tbody>
</table>

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Application Schematic
Table of Contents

1 Features .................................................................. 1
2 Applications .......................................................... 1
3 Description ................................................................ 1
4 Revision History .......................................................... 2
5 Pin Configuration and Functions ......................... 3
6 Specifications .......................................................... 4
   6.1 Absolute Maximum Ratings .................................. 4
   6.2 ESD Ratings—JEDEC Specification ....................... 4
   6.3 ESD Ratings—IEC Specification .............................. 4
   6.4 Recommended Operating Conditions ....................... 4
   6.5 Thermal Information ................................................. 4
   6.6 Electrical Characteristics ........................................... 5
   6.7 Typical Characteristics ............................................. 6
7 Detailed Description ............................................... 7
   7.1 Overview ................................................................... 7
   7.2 Functional Block Diagram ........................................ 7
   7.3 Feature Description ................................................... 7
7.4 Device Functional Modes ............................................ 7
8 Application and Implementation .................................. 8
   8.1 Application Information ............................................... 8
   8.2 Typical Application .................................................... 8
9 Power Supply Recommendations .................................. 9
10 Layout ................................................................. 10
   10.1 Layout Guidelines .................................................. 10
   10.2 Layout Example .................................................... 10
11 Device and Documentation Support .................... 11
   11.1 Documentation Support ............................................ 11
   11.2 Receiving Notification of Documentation Updates .... 11
   11.3 Community Resources ............................................. 11
   11.4 Trademarks ........................................................... 11
   11.5 Electrostatic Discharge Caution ........................... 11
   11.6 Glossary .............................................................. 11
12 Mechanical, Packaging, and Orderable Information .... 11

4 Revision History
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision E (February 2016) to Revision F Page

- Updated the Pin Functions table .......................................................... 3

Changes from Revision D (July 2010) to Revision E Page

- Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section ............................................................................................................. 1
- Deleted Ordering Information table. See POA at the end of the document .......................................................... 1
## Pin Configuration and Functions

![DRL Package 5-Pin SOT Top View](image)

### Pin Functions

<table>
<thead>
<tr>
<th>PIN</th>
<th>TYPE</th>
<th>DESCRIPTION</th>
</tr>
</thead>
<tbody>
<tr>
<td>NO.</td>
<td>NAME</td>
<td>TYPE</td>
</tr>
<tr>
<td>1</td>
<td>I/O1</td>
<td>I/O</td>
</tr>
<tr>
<td>2</td>
<td>GND</td>
<td>—</td>
</tr>
<tr>
<td>3</td>
<td>I/O2</td>
<td>I/O</td>
</tr>
<tr>
<td>4</td>
<td>I/O3</td>
<td>I/O</td>
</tr>
<tr>
<td>5</td>
<td>I/O4</td>
<td>I/O</td>
</tr>
</tbody>
</table>
6 Specifications

6.1 Absolute Maximum Ratings
over operating free-air temperature range (unless otherwise noted)\(^{(1)}\)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Min</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>TJ</td>
<td>125</td>
<td>°C</td>
<td></td>
</tr>
<tr>
<td>Top</td>
<td>–40</td>
<td>125</td>
<td>°C</td>
</tr>
<tr>
<td>Tstg</td>
<td>–55</td>
<td>150</td>
<td>°C</td>
</tr>
</tbody>
</table>

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings—JEDEC Specification

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Value</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>V(_{(ESD)})</td>
<td>±15000</td>
<td>V</td>
</tr>
</tbody>
</table>

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 ESD Ratings—IEC Specification

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Value</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>I(_{pp})</td>
<td>2.5</td>
<td>A</td>
</tr>
<tr>
<td>P(_{pp})</td>
<td>25</td>
<td>W</td>
</tr>
</tbody>
</table>

6.4 Recommended Operating Conditions
over operating free-air temperature range (unless otherwise noted)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Min</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>V(_{IO})</td>
<td>0</td>
<td>5</td>
<td>V</td>
</tr>
<tr>
<td>Operating temperature</td>
<td>–40</td>
<td>125</td>
<td>°C</td>
</tr>
</tbody>
</table>

6.5 Thermal Information

<table>
<thead>
<tr>
<th>THERMAL METRIC(^{(1)})</th>
<th>TPD4E002</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>R(_{JUA}) Junction-to-ambient thermal resistance</td>
<td>220</td>
<td>°C/W</td>
</tr>
<tr>
<td>R(_{WJU}(\text{top})) Junction-to-case (top) thermal resistance</td>
<td>80.3</td>
<td>°C/W</td>
</tr>
<tr>
<td>R(_{WB}) Junction-to-board thermal resistance</td>
<td>42.9</td>
<td>°C/W</td>
</tr>
<tr>
<td>(\psi_{JT}) Junction-to-top characterization parameter</td>
<td>3.2</td>
<td>°C/W</td>
</tr>
<tr>
<td>(\psi_{JB}) Junction-to-board characterization parameter</td>
<td>42.5</td>
<td>°C/W</td>
</tr>
<tr>
<td>R(_{WJU}(\text{bot})) Junction-to-case (bottom) thermal resistance</td>
<td>n/a</td>
<td>°C/W</td>
</tr>
</tbody>
</table>

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.
### 6.6 Electrical Characteristics

\( T_{\text{amb}} = 25^\circ \text{C} \)

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>( V_{\text{BR}} )</td>
<td>I/O breakdown voltage</td>
<td>6.1</td>
<td>7.2</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>( I_{\text{RM}} )</td>
<td>I/O leakage current</td>
<td>0.1  μA</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>( \alpha_T )</td>
<td>Voltage temperature coefficient</td>
<td>4.5  mV/°C</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>( C )</td>
<td>I/O capacitance per line</td>
<td>11   pF</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>( R_d )</td>
<td>Dynamic resistance(^{(1)})</td>
<td>2    Ω</td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

(1) \( R_d \) is measured under reverse breakdown condition with inrush current in the range of 1 A using pulse techniques.
6.7 Typical Characteristics

Figure 1. I/O Capacitance vs Temperature

Figure 2. I/O Capacitance vs Frequency (Typical Values)

Figure 3. Diode Current Across I/O Voltage (Typical Values)
7 Detailed Description

7.1 Overview
The TPD4E002 is a four-channel TVS protection diode array. The TPD4E002 is rated to dissipate contact ESD strikes of ±15 kV, beyond Level 4 as specified in the IEC 61000-4-2 international standard. This device has an 11-pF I/O capacitance per channel, making it ideal for use in data I/O interfaces of up to 100 MHz.

7.2 Functional Block Diagram

7.3 Feature Description
The TPD4E002 is a TVS that provides ESD protection for up to four channels, withstanding up to ±15-kV contact ESD per IEC 61000-4-2 and 2.5-A peak pulse current per IEC 61000-4-5. The monolithic technology yields exceptionally small variations in capacitance between any I/O pin of the TPD4E002. The small footprint is ideal for applications where space-saving designs are important.

7.4 Device Functional Modes
The TPD4E002 device is a passive integrated circuit that triggers when voltages are above \( V_{BR} \) or below the diodes \( V_F \) of approximately –0.5 V. During ESD events, voltages as high as ±15-kV contact ESD can be directed to ground through the internal diodes. Once the voltages on the protected line fall below the trigger levels of TPD4E002 (usually within tens of nano seconds) the device reverts to its high-impedance state.
8 Application and Implementation

NOTE
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI’s customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TPD4E002 device is a TVS diode array typically used to provide a path to ground for dissipating ESD events on high-speed signal lines between a human interface connector and a system. As the current from ESD passes through the TVS, only a small voltage drop is present across the diode. This is the voltage presented to the protected integrated circuit (IC). The triggered TVS holds this voltage, \( V_{\text{CLAMP}} \), to a safe level for the protected IC.

8.2 Typical Application

In a typical design example, one TPD4E002 device is being used to protect an IC against potential ESD from a four-channel human interface port, as shown in Figure 4.

![Figure 4. Typical Application for TPD4E002](image)

8.2.1 Design Requirements

Table 1 lists the parameters for this typical application.

<table>
<thead>
<tr>
<th>DESIGN PARAMETER</th>
<th>VALUE</th>
</tr>
</thead>
<tbody>
<tr>
<td>Signal's voltage range on I/O1, I/O2, I/O3, and I/O4</td>
<td>0 V to 5 V</td>
</tr>
<tr>
<td>Operating frequency</td>
<td>&lt; 100 MHz</td>
</tr>
</tbody>
</table>

8.2.2 Detailed Design Procedure

To begin the design process, some parameters must be decided upon; the designer must know the following:

- Voltage range of the signal on all protected lines
- Operating frequency on all protected lines

8.2.2.1 Signal Range on I/O1 Through I/O2

The TPD4E002 device has 4 identical protection channels for signal lines. The symmetry of the device provides flexibility when selecting which of the four I/O channels will protect which signal lines. Any I/O supports a signal range of 0 V to 5 V and up to 100 MHz.
8.2.3 Application Curves

![Graph showing ESD Clamp Voltage at I/O Pins: IEC6100-4-2 15-kV Contact Discharge](image)

![Graph showing Pulse Waveform (8/20-µs Pulse)](image)

9 Power Supply Recommendations

The TPD4E002 is a passive ESD protection device and there is no need to power it. Do not violate the maximum voltage specifications for each pin.
10 Layout

10.1 Layout Guidelines

- The optimum placement is as close to the connector as possible.
  - EMI during an ESD event can couple from the trace being struck to other nearby unprotected traces, resulting in early system failures.
  - The PCB designer must minimize the possibility of EMI coupling by keeping any unprotected traces away from the protected traces, which are between the TVS and the connector.
- Route the protected traces as straight as possible.
- Eliminate any sharp corners on the protected traces between the TVS and the connector by using rounded corners with the largest radii possible.
  - Electric fields tend to build up on corners, increasing EMI coupling.

Use external and internal ground planes and stitch them together with VIAs as close to the GND pin of TPD4E002 as possible. This allows for a low impedance path to ground so that the device can properly dissipate an ESD event.

10.2 Layout Example

Legend

- VIA to Internal GND Plane
- Pin to GND
- Top Layer GND Plane

Figure 7. TPD4E002 Example Layout
11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

For related documentation see the following:

- Reading and Understanding an ESD Protection Datasheet
- ESD Layout Guide

11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on Alert me to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI’s views; see TI’s Terms of Use.

TI E2E™ Online Community  TI’s Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support  TI’s Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.4 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

11.5 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.
## Packaging Information

<table>
<thead>
<tr>
<th>Orderable Device</th>
<th>Status</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>Package Qty</th>
<th>Eco Plan</th>
<th>Lead/Ball Finish</th>
<th>MSL Peak Temp</th>
<th>Op Temp (°C)</th>
<th>Device Marking</th>
<th>Samples</th>
</tr>
</thead>
<tbody>
<tr>
<td>TPD4E002DRL2</td>
<td>ACTIVE</td>
<td>SOT-5X3</td>
<td>DR1</td>
<td>5</td>
<td>4000</td>
<td>Green</td>
<td>CU NIPDAUAG</td>
<td>Level-1-260C-UNLIM</td>
<td>-40 to 85</td>
<td>28S</td>
<td>Samples</td>
</tr>
<tr>
<td>TPD4E002DRLR</td>
<td>ACTIVE</td>
<td>SOT-5X3</td>
<td>DR1</td>
<td>5</td>
<td>4000</td>
<td>Green</td>
<td>CU NIPDAUAG</td>
<td>Level-1-260C-UNLIM</td>
<td>-40 to 85</td>
<td>28S</td>
<td>Samples</td>
</tr>
</tbody>
</table>

1. The marketing status values are defined as follows:
   - **ACTIVE**: Product device recommended for new designs.
   - **LIFEBUY**: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
   - **NRND**: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
   - **PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.
   - **OBSOLETE**: TI has discontinued the production of the device.

2. **RoHS**: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
   - **RoHS Exempt**: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
   - **Green**: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

3. **MSL, Peak Temp.** - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

4. There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

5. Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

6. Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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<table>
<thead>
<tr>
<th>Device</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>SPQ</th>
<th>Reel Diameter (mm)</th>
<th>Reel Width W1 (mm)</th>
<th>A0 (mm)</th>
<th>B0 (mm)</th>
<th>K0 (mm)</th>
<th>P1 (mm)</th>
<th>W (mm)</th>
<th>Pin1 Quadrant</th>
</tr>
</thead>
<tbody>
<tr>
<td>TPD4E002DRL2</td>
<td>SOT-5X3</td>
<td>DRL</td>
<td>5</td>
<td>4000</td>
<td>180.0</td>
<td>8.4</td>
<td>1.98</td>
<td>1.78</td>
<td>0.69</td>
<td>4.0</td>
<td>8.0</td>
<td>Q2</td>
</tr>
<tr>
<td>TPD4E002DRLR</td>
<td>SOT-5X3</td>
<td>DRL</td>
<td>5</td>
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<td>1.98</td>
<td>1.78</td>
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<td>4.0</td>
<td>8.0</td>
<td>Q3</td>
</tr>
<tr>
<td>Device</td>
<td>Package Type</td>
<td>Package Drawing</td>
<td>Pins</td>
<td>SPQ</td>
<td>Length (mm)</td>
<td>Width (mm)</td>
<td>Height (mm)</td>
<td></td>
<td></td>
<td></td>
<td></td>
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</tr>
<tr>
<td>TPD4E002DRL2</td>
<td>SOT-5X3</td>
<td>DRL</td>
<td>5</td>
<td>4000</td>
<td>183.0</td>
<td>183.0</td>
<td>20.0</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>TPD4E002DRLR</td>
<td>SOT-5X3</td>
<td>DRL</td>
<td>5</td>
<td>4000</td>
<td>183.0</td>
<td>183.0</td>
<td>20.0</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

*All dimensions are nominal*
NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs.
Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0.15 per end or side.
D. JEDEC package registration is pending.
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC-7351 is recommended for alternate designs.
D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
E. Maximum stencil thickness 0.127 mm (5 mils). All linear dimensions are in millimeters.
F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.
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